NSN 5962-01-028-2081

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Body	Len	gth:
D - 4	0	745

Between 0.745 inches and 0.785 inches

Body Width:

Between 0.240 inches and 0.260 inches

Body Height:

Between 0.095 inches and 0.140 inches

Maximum Power Dissipation Rating:

500.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Receiver fscm 50464

Features Provided:

Hermetically sealed and monolithic and high voltage and positive outputs and edge triggered and w/clear and resettable and w/enable

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

Dual 3 input

Case Outline Source And Designator:

-0-001-ae joint electron device engineering council

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 20.5 volts power source

Memory Device Type:

Rom

Test Data Document:

81349-mil-std-883 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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